

isc Silicon PNP Power Transistor

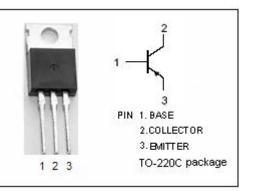
2SB565

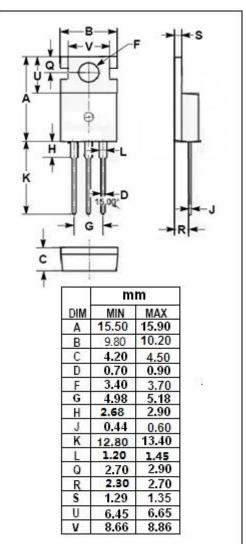
DESCRIPTION

- Low Collector Saturation Voltage
 :V_{CE(sat)}= -1.0(V)(Max)@I_C= -2A
- Collector-Emitter Breakdown Voltage-
- : V_{(BR)CEO}= -50V(Min)
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

• Designed for low frequency power amplifier and power switching applications.





ABSOLUTE MAXIMUM RATINGS(T_a=25℃)

SYMBOL	PARAMETER	VALUE	UNIT
V _{сво}	Collector-Base Voltage	-50	V
V _{CEO}	Collector-Emitter Voltage	-50	V
V _{EBO}	Emitter-Base Voltage	-4	V
lc	Collector Current-Continuous	-4	А
I _{CM}	Collector Current-Peak	-8	А
Pc	Total Power Dissipation @ $T_c=25^{\circ}C$	40	W
TJ	Junction Temperature 150		°C
T _{stg}	Storage Temperature Range -55~150		°C

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ELECTRICAL CHARACTERISTICS

$T_c=25^{\circ}C$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	МАХ	UNIT
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	I _C = -30mA; R _{BE} = ∞	-50			V
V _{(BR)CBO}	Collector-Base Breakdown Voltage	I _C = -10 μ Α; I _E = 0	-50			V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	I _E = -10 μ Α; I _C = 0	-4			V
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = -2A; I _B = -0.2A			-1.0	V
V _{BE(sat)}	Base-Emitter Saturation Voltage	I _C = -2A; I _B = -0.2A			-1.2	V
Ісво	Collector Cutoff Current	V _{CB} = -50V ; I _E = 0			-1	μ Α
h _{FE-1}	DC Current Gain	I _C = -1A; V _{CE} = -4V	60		200	
h _{FE-2}	DC Current Gain	I _C = -0.1A; V _{CE} = -4V	35			

h_{FE-1} Classifications

В	С
60-120	100-200

NOTICE:

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